

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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800nm Avalanche Photodiode

Product No: MTAPD-07-003

Peak Sensitivity Wavelength: 800nm

The MTAPD-07-003 is a circular (Φ230um) 0.04 mm² active area Avalanche Photodiode with optimized sensitivity at 800nm & housed in a LCC6 SMD package. It is well suited for applications requiring High Speed & Low Noise in visible-near IR applications.

FEATURES

>Fast Rise Time

>Ultra Low Noise

>Low Capacitance

>High Gain

>Optimum Gain M100

>Operating Voltages:

Other Voltages Available

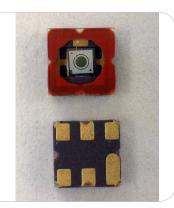
120v - 160v

>Optical rangefinders

> High speed optical communications

>Medical Equipment

>Bar Code Readers



Absolute Maximum F	Pb				
ITEMS	SYMBOL	RATINGS	UNIT		lead-freé
Storage Temperature	Tstg	-55 ~ +125	°C		
Operating Temperature	Topr	-20 ~ +85	°C		
Power Dissipation	Pd	1	mW		
Forward Current	If	1	mA		
Operating Voltage	Vop	0.95 x Vbr	V		
Solder Reflow Temperature *1	Stemp	260	°C		

*1: Time 5 Sec max

Electrical & Optical Characteristics (Ta=23°C)										
ITEMS	SYMBOL	CONDITIONS	MIN.	TYP	MAX.	UNIT				
Spectral Response	λ			400 - 1100		nm				
Active Area				Diameter 230		um				
Responsivity	Re	λ=800nm, φe=1uW, M=100	35	50		A/W				
Rise Time	t_R	f=1MHz, RL=50 Ω , λ =800nm		0.3		ns				
Dark Current	I_{D}	M=100	0.02	0.05	0.4	nA				
Capacitance	Cj	M=100, f=1MHz		1.5		pF				
Optimal Gain	М			100						
Breakdown Voltage	Vbr	IR=2uA	80		200	V				
Temperature Coefficient		Tc=-40°C - 85°C		0.6		V/°C				

2015-10-30



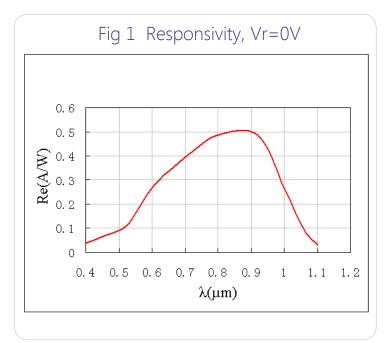
800nm Avalanche Photodiode

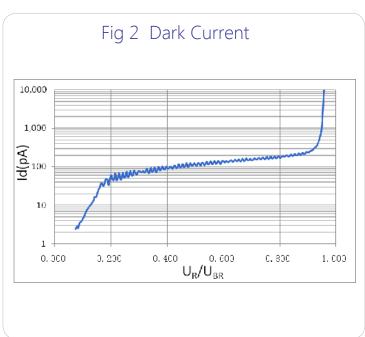
Product No: MTAPD-07-003

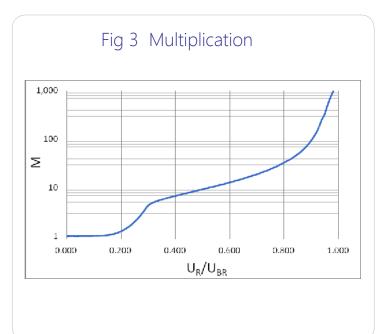
LCC6 SMD Package Dimensions (6 Pin) MTAPD-07-003 Vbr=120-160V The distance from photosensitive surface to the bottom Pad 1,2,3,4,6: APD+ (Anode) Pad 5: APD- (Cathode)

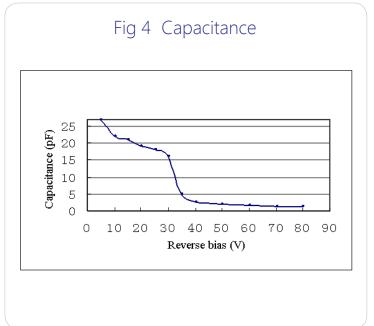
Unit: mm, Tolerance: ±0.2

Product No: MTAPD-07-003







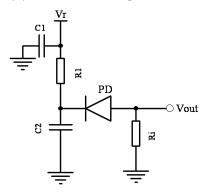




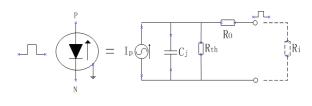
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Applications Diagram



Equivalent Circuit Diagram



Notes: C1 - Filter capacitor, filter noise from Vr.

C2 - bypass capacitor, the loop to ground for AC signal.

R1 - current-limiting resistor, protect APD from higher voltage.

Ri - sampling resistor, convert the current signal into a voltage signal.

ESD SENSITIVE

The information contained herein is subject to change without notice.

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